TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC7SET14F,TC7SET14FU

Schmitt Inverter

Features

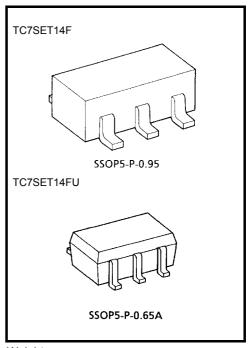
• High speed t_{pd} = 5.0 ns (typ.) at V_{CC} = 5 V

 $ac \lor CC = 0 \lor C$

• Low power dissipation I_{CC} = 2 μA (max) at T_{a} = 25°C

Compatible with TTL outputs...VIL = 0.8 V (max.)
 VIH = 2.0 V (min.)

• 5.5V tolerant input.



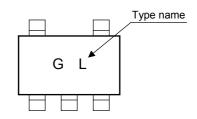
Weight

SSOP5-P-0.95 : 0.016 g (typ.) SSOP5-P-0.65A : 0.006 g (typ.)

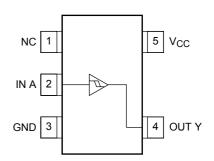
Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V _{CC}	-0.5~7.0	V
DC input voltage	V _{IN}	-0.5~7.0	V
DC output voltage	V _{OUT}	-0.5~V _{CC} + 0.5	V
Input diode current	l _{IK}	-20	mA
Output diode current	lok	±20	mA
DC output current	lout	±25	mA
DC V _{CC} /ground current	Icc	±50	mA
Power dissipation	PD	200	mW
Storage temperature	T _{stg}	-65~150	°C
Lead temperature (10 s)	TL	260	°C

Marking



Pin Assignment (top view)



Logic Diagram



Truth Table

INPUT	OUTPUT
Α	Y
L	Н
Н	L

Recommended Operating Conditions

Characteristics	Symbol	Rating	Unit
Supply voltage	V _{CC}	4.5~5.5	V
Input voltage	V _{IN}	0~5.5	V
Output voltage	V _{OUT}	0~Vcc	٧
Operating temperature	T _{opr}	-40~85	°C
Input rise and fall time	dt/dv	0~20	ns/V

DC Electrical Characteristics

					-	Га = 25°C	;	Ta = -40~85°C		
Characteristics	Symbol	Test Condition		V _{CC} (V)	Min	Тур.	Max	Min	Max	Unit
Positive Threshold	\/-			4.5	_	_	1.90	_	1.90	
Voltage	V _P	_	-	5.5	_		2.10	_	2.10	
Negative Threshold	V.			4.5	0.50	_	_	0.50	_	V
Voltage	V _N	_	-	5.5	0.60	_	_	0.60	_	V
Hysteresis Voltage V _H			4.5	0.40	_	1.40	0.40	1.40	-	
	_	_		0.40	_	1.50	0.40	1.50		
I Bala Javas and and analysis and	V	\ \ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\	$I_{OH} = -50 \mu A$	4.5	4.4	4.5	_	4.4	_	
High-level output voltage	VoH	$V_{IN} = V_{IL}$	I _{OH} = -8 mA	4.5	3.94	_	_	3.80	_	V
Low-level output voltage V _{OL}	Va		$I_{OL} = 50 \mu A$	4.5	_	0.0	0.10	_	0.10	V
	VOL VIN	$V_{IN} = V_{IH}$	I _{OL} = 8 mA	4.5	_	_	0.36	_	0.44	
Input leakage current	I _{IN}	V _{IN} = 5.5 V or G	0~ 5.5	_	_	±0.1	_	±1.0	μА	
	I _{CC}	V _{IN} = V _{CC} or GND		5.5	_	_	2.0	_	20.0	μА
Quiescent supply current	I _{CCT}	Per Input Other Input	:V _{IN} = 3.4 V :V _{CC} or GND	5.5	_	_	1.35	_	1.50	mA

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AC Characteristics (input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = -40~85°C		- Unit	
			V _{CC} (V)	C _L (pF)	Min	Тур.	Max	Min	Max	Ullit
Propagation delay time	t _{pLH} t _{pHL}		5.0 ± 0.5	15	_	5.0	7.6	1.0	9.0	- ns
				50	_	6.5	9.6	1.0	11.0	
Input capacitance	C _{IN}				_	4	10	_	10	pF
Power dissipation capacitance	C _{PD}			(Note)	_	18	_	_	_	pF

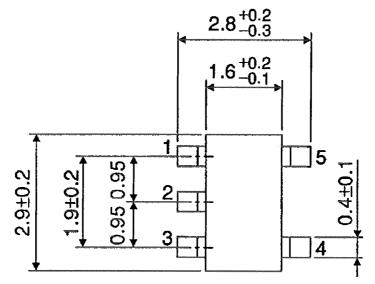
Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

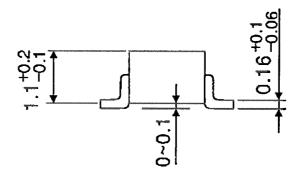
Average operating current can be obtained by the equation:

$$I_{CC \text{ (opr)}} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$$

Package Dimensions

SSOP5-P-0.95 Unit: mm



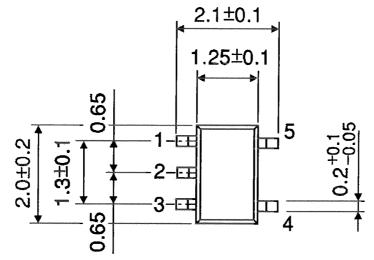


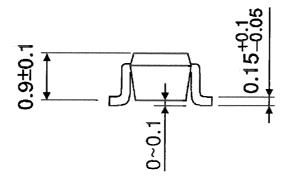
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Weight: 0.016 g (typ.)

Package Dimensions

SSOP5-P-0.65A Unit: mm





Weight: 0.006 g (typ.)

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